Infrared Halle ect in underdoped and optim ally doped LSCO

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We report a study of magneto-optical properties in the mid-infrared region of a series of $La_2 \ _x Sr_x CuO_4$ samples with hole doping level ranging from severely underdoped (x = 0.03)to optim ally doped (x = 0.15). The Faraday rotation and circular dichroism are measured in a magnetic eld of 8 Tesla and in a temperature range between 30K and 300K. The doping and temperature dependence of infrared H all angle is found to be understood within a simple D rude m odel. A significant increase of H all frequency is observed when the hole doping level is reduced from optim all doping, which is compared with m odels of the pseudogap.

As the hole doping in cuprate superconductors is reduced below optimal T_c they enter a pseudogap phase before they ultimately undergo a transition to a Mott insulating ground state. W hile the pseudogap phase exhibits evidence for a partial gapping of the Ferm i surface in many expereiments its character is otherwise poorly understood. It is this mysterious pseudogap phase that attracts the greatest attention in the guest for understanding the mechanism for high T_c. Many di erent scenarios have been proposed for this state [1]. One of the proposals for partially gapping the Ferm i surface is the form ation of a density wave state. In this scenerio the large Ferm i surface of the optim ally doped system develops energy gaps at the magnetic Brillioun zone boundaries and breaks up into sm all pockets. How ever no evidence of energy gaps have been reported from IR studies and the evidence from ARPES is controversial. Recently, Rigaletal. [2] observed a dram atic increase of the Hall frequency in underdoped YBa₂Cu₃O_{6+x} (YBCO) sam ples, which is consistent with the presence of Ferm ipockets due to a partial gapping of the original Ferm i surface. An alternative interpretation of the increase in the Hall frequency follows from recent work by H.Kontaniwhich includes vertex corrections in the calculation of the optical conductivity of the cuprates based on the uctuation exchange model of the interactions [3, 4]. In any case the analysis of the results in YBCO is complicated by the existence of CuO chains. Therefore it is highly desirable to repeat these m agneto-optical studies with other cuprates.

La_{2 x}Sr_xCuO₄ (LSCO) is an idealcom pound to study. It has a relatively simple lattice with one layer of CuO₂ plane, and without the complication of CuO chain as in YBCO. And a wide range of doping level is readily available. Of particular interest is the severely underdoped LSCO, which is predicted by conventional phase diagram of cuprates to be anti-ferrom agnetic insulator. However recently angle-resolved photoem ission (ARPES) [5], DC transport [6] and Hall e ect [7] m easurem ents show evidences of m etallic behavior even for x = 0.02 sample. Furtherm ore, m easurem ent of anisotropy of DC [8] and optical [9] conductivity of de-tw inned sam ples indicates possible existence of charge stripes. In this letter we report the study of m agneto-optical properties in the m idinfrared region of a series of LSCO sam ples ranging from slightly hole doped to optim ally doped, by m easuring the Faraday rotation and circular dichroism in a m agnetic

eld of 8 Tesla and in a tem perature range between 30K and 300K.We found that the doping and tem perature dependence of H all angle can be understood well understood with a simple D rude m odel. A signi cant increase of H all frequency is observed when the hole doping level is reduced from optim al doping, which is consistent with drastic reduction of the volume of Ferm i surface in the underdoped sample.

The La_{2 x}Sr_xCuO₄ samples used in this study are severely underdoped (x = 0.03), underdoped (x = 0.10) and optimally doped (x = 0.15) thin Im s grown on SrTiO₃ substrates by pulsed laser deposition (PLD). The x = 0.03 samples does not show superconducting transition, while the other two samples have T_c of 32K and 35K, respectively. The thin Im s have thickness ranging from 2500 A to 3800 A.

In the infrared Hall study various magneto-optical properties such as Hall angle $_{\rm H}$ and Hall conductivity $_{\rm Xy}$ are obtained by measuring the complex Faraday angle, whose real and in aginary parts correspond to Faraday rotation and circular dichroism when the linearly polarized laser beam from a CO₂ laser pass through the sample. In the mid-infrared region (900cm 1 1100cm 1) where the measurements are taken, the typical value of Faraday angle is at the order 10 4 10 5 radians per Tesla. Such a precision measurement of Faraday angle requires a very sensitive technique which is achieved by using a ZnSe photoelastic modulator to analyze the change in the polarization of the laser beam [10].

It has been proved that the optical Hall angle $\tan_{H}(!)_{H}(!) = xy(!) = (!)$ is a response function with it own f-sum rule [11]. Therefore similar to other response function like optical conductivity, the simplest

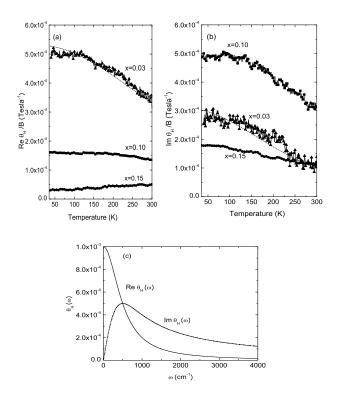


FIG.1: (a) and (b): Temperature dependence of real (a) and imaginary (b) parts of Hallangle $_{\rm H}$ at ! = 1087cm 1 for x= 0.03, 010 and 0.15 samples. (c): Simulated frequency dependence of Hallangle based on simple D rude model with $_{\rm H}$ = 500cm 1 ;! $_{\rm H}$ = 0.5.

functional form of Hallangle is that of the D rude m odel:

$$_{\rm H}$$
 (!) = $\frac{!_{\rm H}}{!_{\rm H}}$; (1)

where the Hall scattering rate $_{\rm H}$ is a di erent integral [12] of (k) along the Ferm i surface than that of the regular scattering rate, while the Hall frequency !_H is related to the cyclotron frequency in the sim plemetal. Study in past few years suggests that the D rudem odel of Hall angle works well for sim plemetal lm s like Au and Cu, as well as hole doped cuprates with various doping, except for electron doped Pr₂ $_{\rm x}$ Ce_xCuO₄, in which there is evidence of the form ation of a spin-density wave state in the underdoped region.

Shown in gure 1 (a) and (b) are the temperature dependence of real(a) and imaginary (b) parts of the com – plex Hall angles $_{\rm H}$, measured at ! = 1087cm $^{-1}$, for x = 0.03, x = 0.10 and x = 0.15 samples, respectively. W hen the hole doping level is increased from the severely underdoping level at x = 0.03 to the optim ally doped level at x = 0.15, the real part of $_{\rm H}$ decrease monotonically with increasing doping, while the imaginary part

rst increases, then decreases with increasing doping. The observed doping dependence of $_{\rm H}$ can be understood if one consult gure 1(c), which is a plot of $_{\rm H}$ (!) based on the simple D rude m odel (equation 1). Sim ilar

to otherm one familiar response function like optical conductivity, the real part of $_{\rm H}$ (!) is a Lorentzian centered at ! = 0 with half width $_{\rm H}$, while the imaginary part reaches its peak at $_{\rm H}$. Therefore the doping dependence of $_{\rm H}$ can be understood if we assume that $_{\rm H}$ of the x = 0.03 sample is larger than ! = 1087cm⁻¹ and the other two samples have $_{\rm H}$ sm aller than !.

P botted in gure 2 (a) are the real parts of inverse H all angles as functions of square of tem perature for the three sam ples, in tem perature range from 30K to 300K, as well as their linear ts. Since $_{\rm H}^{-1}$ cot $_{\rm H}$ for sm all $_{\rm H}$, it indicates that cot $_{\rm H}$ / T² for all three sam ples, which is consistent with recent result from DC H all e ect [7]. The T² linear dependence of cot $_{\rm H}$, and therefore the H all scattering rate $_{\rm H}$ can be demonstrated by tting the tem perature dependence of $_{\rm H}$ by the sim ple D rude m odel:

Re_H(T) =
$$\frac{!_{H-H}(T)}{!_{H}(T) + !_{2}^{2}}$$
; Im_H(T) = $\frac{!_{H}!}{!_{H}(T) + !_{2}^{2}}$; (2)

with a Hall scattering rate linearly dependent on T^2 : _H (T) = a + bT². The dashed lines in gure 1(a) and (b) show such a t for x=0.03 data, with tting parameters !_H = 1.25cm¹, a = 1793cm¹ and b = 1.89 10² cm¹K². This demonstrates that the transport revealed by Hall angle can be well described by a simple D rude model and is similar to that of a conventional Fermi liquid, even for the severely underdoped x = 0.03 sample.

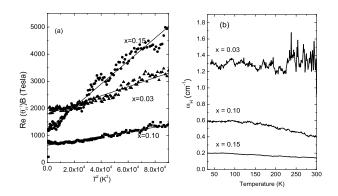


FIG.2: (a) Realpart of inverse H all angle $_{\rm H}^{-1}$ m easured at ! = 1087cm $^{-1}$ for x = 0.03;0:10 and 0.15 sam ples. (b): H all frequencies ! $_{\rm H}$ of the x= 0.03, 0.10 and 0.15 sam ples.

Shown in gure 2 (b) is the tem perature dependence of H all frequencies $!_{\rm H}$ for the three sam ples obtained from D rude analysis: $!_{\rm H} = != {\rm Im}_{\rm H}^{-1}$. A weak tem perature dependence in $!_{\rm H}$ is observed in all three sam ples. However, drastic increase of $!_{\rm H}$ is observed when the hole doping level is reduced, con mming the early observation [2] of sim ilar trend in a set of underdoped YBCO sam ples. In the case of YBCO, the analysis is com plicated by the existence of conducting CuO chains, whose

contribution to optical conductivity is di cult to be reliably subtracted. For a Ferm i-liquid the Hall frequency can be expressed in term s of integrals of the Ferm i velocity over the Ferm i surface as [12]:

$$I_{H} = \frac{eB}{hc} \frac{dSe_{z} v(k) \frac{d}{dk}v(k)}{dSjv(k)j}; \qquad (3)$$

Therefore the observed strong increase in the Hall frequency as the hole doping is reduced from optim aldoping suggests that the Ferm i surface topography changes signi cantly. One possible scenario is the gapping out of part of Ferm i surface in underdoped samples by the form ation of a density wave state. In case of underdoped LSCO, there is evidence from ARPES [5] suggesting that, for severely underdoped x = 0.03 sample, a signi cant fraction of the large Ferm i surface which is observed in optim ally doped sam ples is destroyed and the rem aining small portion is a small pocket near (0:42;0:42). The observed increase in Hall frequency in the density wave state is predicted by a calculation [15] within the ddensity wave (DDW)m odel using the sem iclassical Boltzm ann theory in the weak eld lim it [16]. However, there is an alternative interpretation in terms of the e ects of interactions on the optical magneto-conductivity. Recent work by Kontani [4] based on the uctuation exchange model in which vertex corrections are included in the calculation of the Hall conductivity also shows a D rude like response of the Hall angle and an increase of $!_{\rm H}$ by 70% when doping level is reduced from x = 0.20 to x = 0.10. In choosing between these two interpretations it is notew orthy that evidence for a density wave gap has not been reported for the hole doped cuprates. By contrast $Pr_{2} \times Ce_{x}CuO_{4}$, an electron doped cuprate, which exhibits a gap like feature in xx, displays a di erent xy response than the hole doped cuprates in which features associated with density wave gap excitations are seen [17, 18].

In sum m ary, we studied the infrared H alle ect in a series of LSCO samples with the hole doping level ranging from severely underdoped (x = 0.03) to optimally doped (x = 0.15). We found that the doping and temperature dependence of H all angle can be well described with a simple D rude m odel. A signi cant increase of the H all frequency is observed when the hole doping level is reduced from optimal doping. This is not a sample of Fermi surface in the underdoped sample due to the form ation of a

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